

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 118807		APPLICATION NO. 10/782,975	
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)				APPLICANTS Kimihiro MAEMURA			
				FILING DATE February 24, 2003			
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	
<i>MA</i>	1	6,587,381	07/01/2003	Kanai et al.	<i>11</i>	<i>11</i>	
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<i>MA</i>	3	6,646,916	11/11/2003	Kamei	<i>11</i>	<i>11</i>	
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<i>MA</i>	6	6,707,720	03/16/2004	Kamei et al.	<i>11</i>	<i>11</i>	
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<i>MA</i>	11	6,744,106	06/01/2004	Kanai	<i>11</i>	<i>11</i>	
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Date: July 14, 2004

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EXAMINER				DATE CONSIDERED		
<i>M. Maemura</i>				05/23/05		
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.						

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<i>UH</i>	14	Chang et al., "A New SONOS Memory Using Source-Side Injection for Programming," IEEE Electron Device Letters, Vol. 19, No. 7, pp. 253-255, July 1998
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EXAMINER <i>Maemura</i>	DATE CONSIDERED 03/23/05
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